DOMINANT™
Opto Technologies
Innovating Illumination

DATA SHEET:

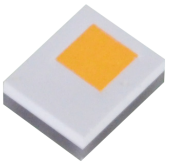
NagaJo 2025

InGaN : J1ZY-PZHS

NagaJo

With continuous driven state of art mindset NagaJo is released to support today's market demand for new performance setting and economical standards. Its compact and robust in design, high efficiency, NagaJo also contributes to weight reduction. The small package outline with enhanced durability, enhanced heat dissipation and superior light performance.

Features:



> Super high brightness surface mount LED automotive exterior applications.
> 120° viewing angle.
> Compact package outline (LxWxH) of 2.0 x 2.5 x 0.99mm.
> Small LES 1.15 x 1.15mm.
> Low thermal resistance, $R_{thJS;}$ 3.6K/W.
> Superior corrosion robustness.
> Compatible to IR reflow soldering.
> Compliance to automotive standard; AEC-Q102.
> Qualified according to JEDEC moisture sensitivity Level 2.
> Environmental friendly; RoHS compliance.

Applications:

> Automotive: Turn Signal

Electrical Characteristics at Tj=25˚C

Part Number	Color	Viewing Angle˚	Luminous Flux @ 1A (lm) Appx. 1.2		
			Min.	Typ.	Max.
● J1ZY-PZHS-8W8X-1	InGaN Yellow	120	168.0	205.0	234.0

● Not for new design

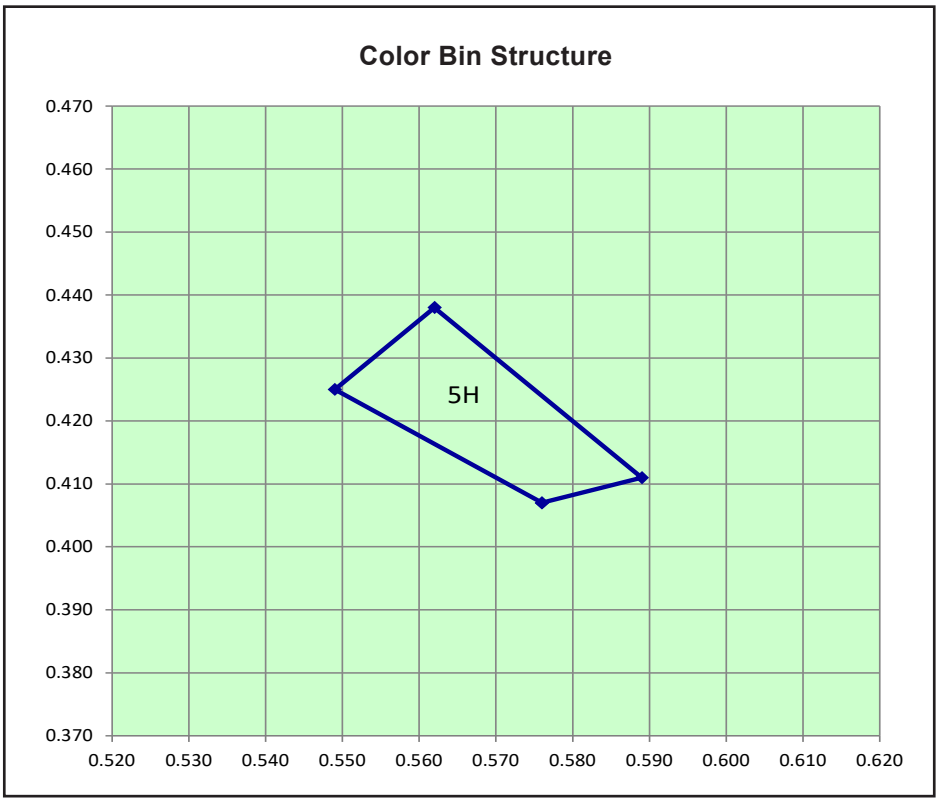
Electrical Characteristics at Tj=25˚C

Part Number	Vf @ If = 1A Appx. 3.1		
	Min. (V)	Typ. (V)	Max. (V)
J1ZY-PZHS	2.9	3.2	3.5

Absolute Maximum Ratings

	Maximum Value	Unit
DC forward current	1.2	A
Peak pulse current; (T_s=55°C, tp ≤ 100µs, Duty cycle = 0.03)	1.5	A
Reverse voltage; Ir_{max} = 10µA	Not for Reverse Bias	V
ESD threshold (HBM)	8	kV
LED junction temperature	150	˚C
Operating temperature	-40 … +125	˚C
Storage temperature	-40 … +125	˚C
Thermal resistance (Rated current = 1A, Ts=25˚C) - Real Thermal Resistance Junction / solder point, $R_{th\ JS\ real}$ (typ = 3.6)	4.6	K/W
- Electrical Thermal Resistance Junction / solder point, $R_{th\ JS\ el}$ (typ = 3.2)	4.0	K/W

Color Grouping *Appx. 2.1*



Bin		1	2	3	4
5H	Cx	0.5760	0.5490	0.5620	0.5890
	Cy	0.4070	0.4250	0.4380	0.4110

InGaN wavelength is very sensitive to drive current. Operating at lower current is not recommended and may yield unpredictable performance current pulsing should be used for dimming purposed.

Luminous Flux Group at Tj=25˚C

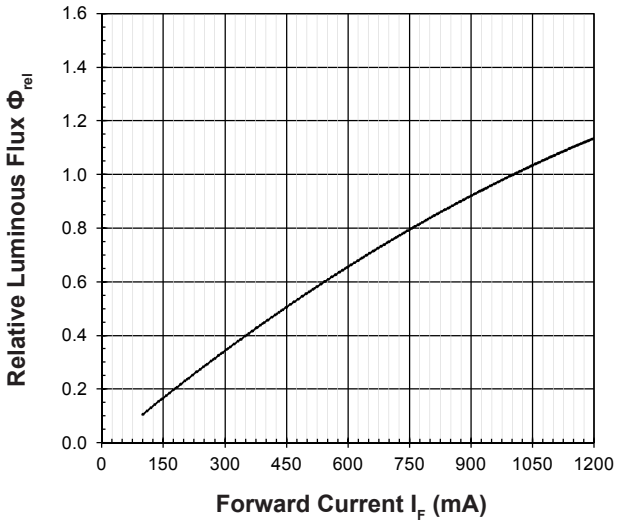
Brightness Group	Luminous Flux *Appx. 1.2* (lm)
8W	168.0 ... 180.0
9W	180.0 ... 192.0
6X	192.0 ... 205.0
7X	205.0 ... 219.0
8X	219.0 ... 234.0

Vf Bining (Optional)

Vf Bin @ 1A	Forward Voltage (V) *Appx. 3.1*
VD8	2.90 ... 3.10
VD9	3.10 ... 3.30
VE1	3.30 ... 3.50

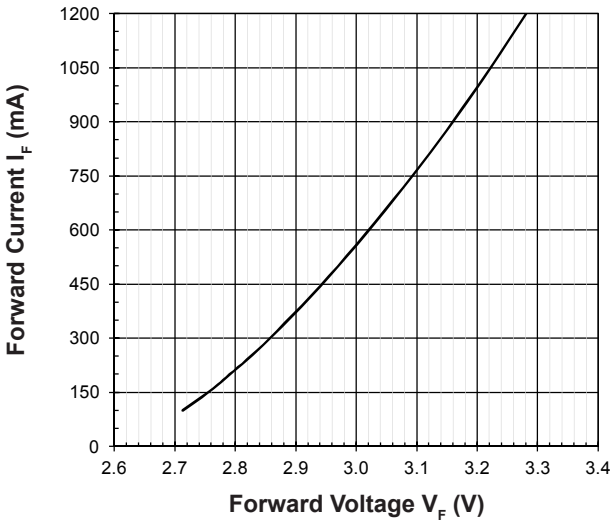
Relative Luminous Flux Vs Forward Current

$\Phi_V/\Phi_V(1A) = f(I_F)$; $T_j = 25°C$



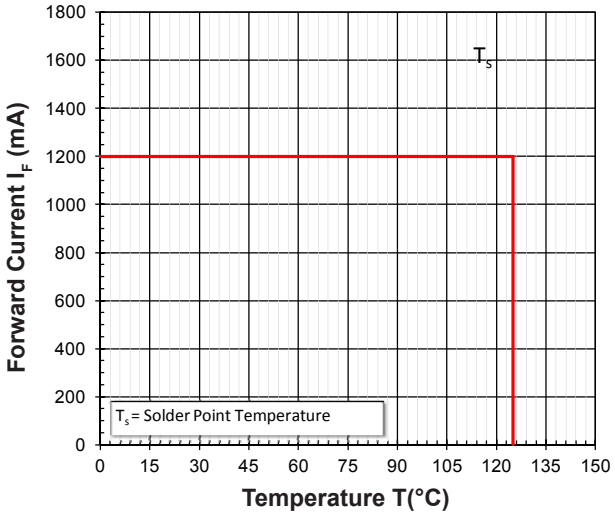
Forward Current Vs Forward Voltage

$I_F = f(V_F)$; $T_j = 25°C$



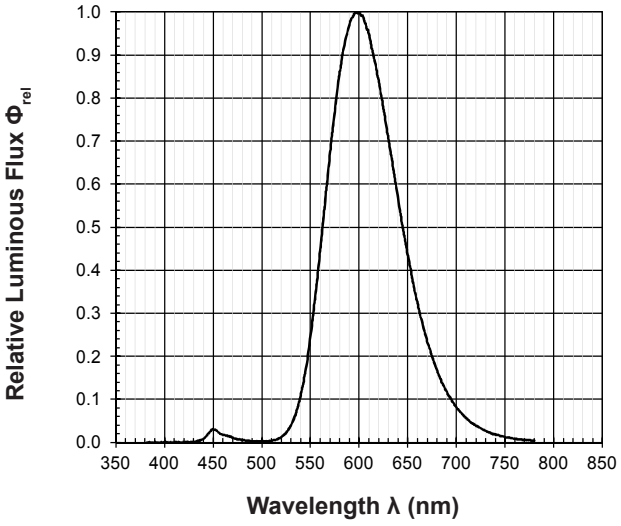
Maximum Current Vs Temperature

$I_F = f(T)$



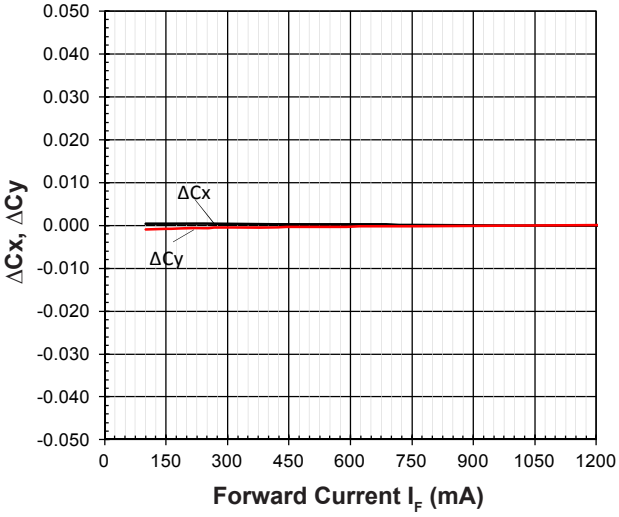
Relative Spectral Emission

$\Phi_{rel} = f(\lambda)$; $T_j = 25°C$; $I_F = 1A$



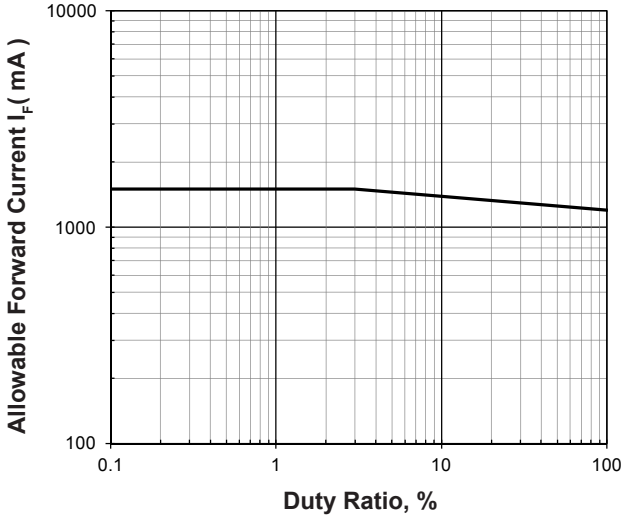
Chromaticity Coordinate Shift Vs Forward Current

$\Delta Cx, \Delta Cy = f(I_F); T_j = 25°C$

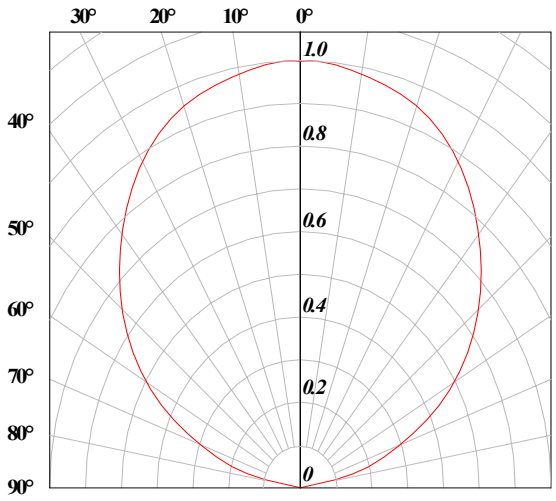


Allowable Forward Current Vs Duty Ratio

($T_s = 55°C$; $t_p \leq 100\mu s$)

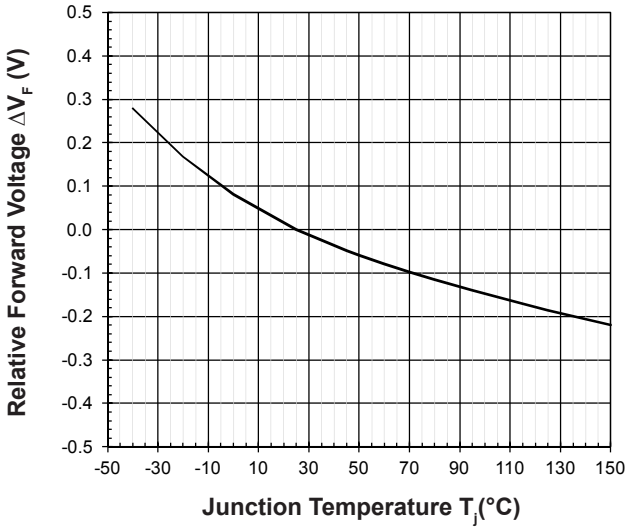


Radiation Pattern



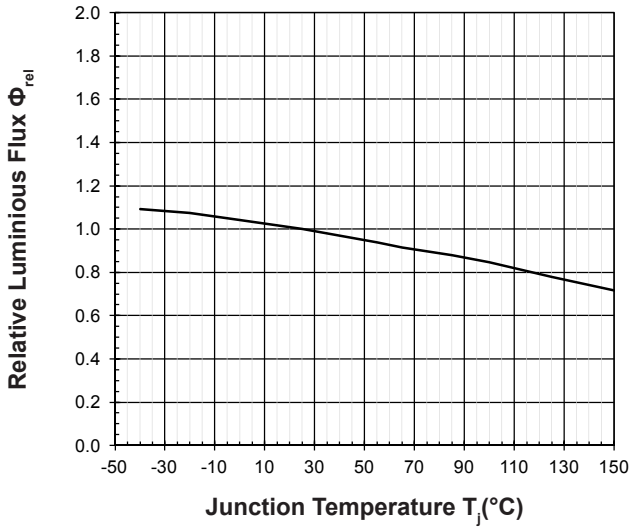
Relative Forward Voltage Vs Junction Temperature

$\Delta V_F = V_F - V_F(25°C) = f(T_j)$; I_F =1A



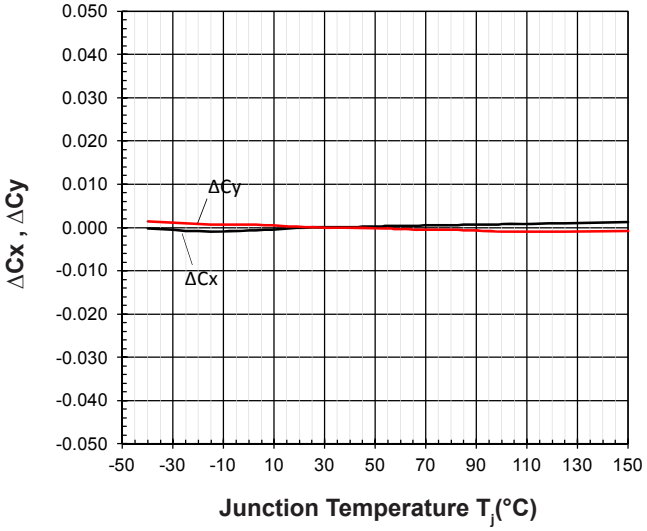
Relative Luminious Flux Vs Junction Temperature

$\Phi V/\Phi V(25°C) = f(T_j)$; I_F = 1A

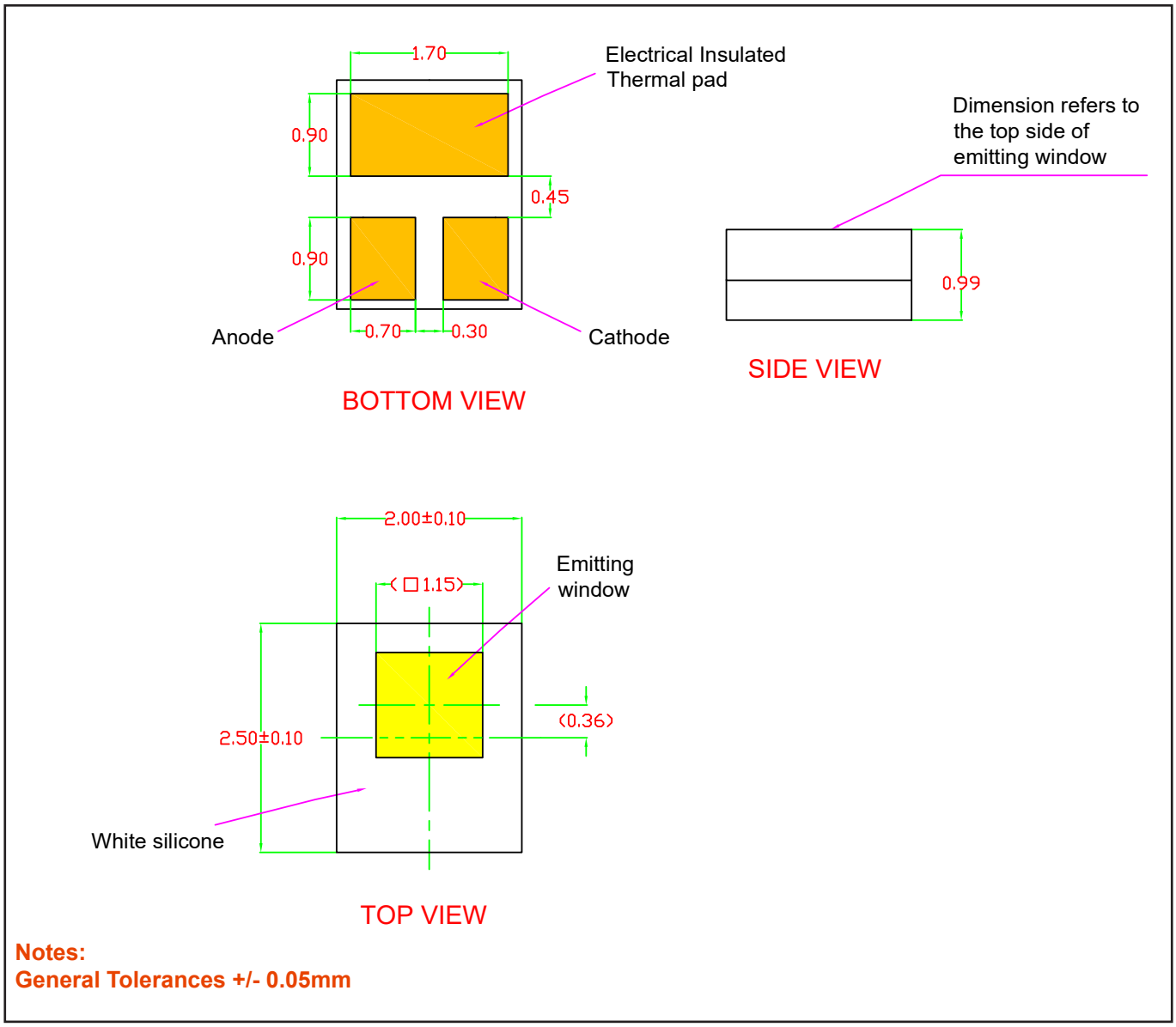


Chromaticity Coordinate Shift Vs Junction Temperature

$\Delta Cx, \Delta Cy = f(T_j)$; I_F = 1A



NagaJo 2025 InGaN : J1ZY-PZHS Package Outlines

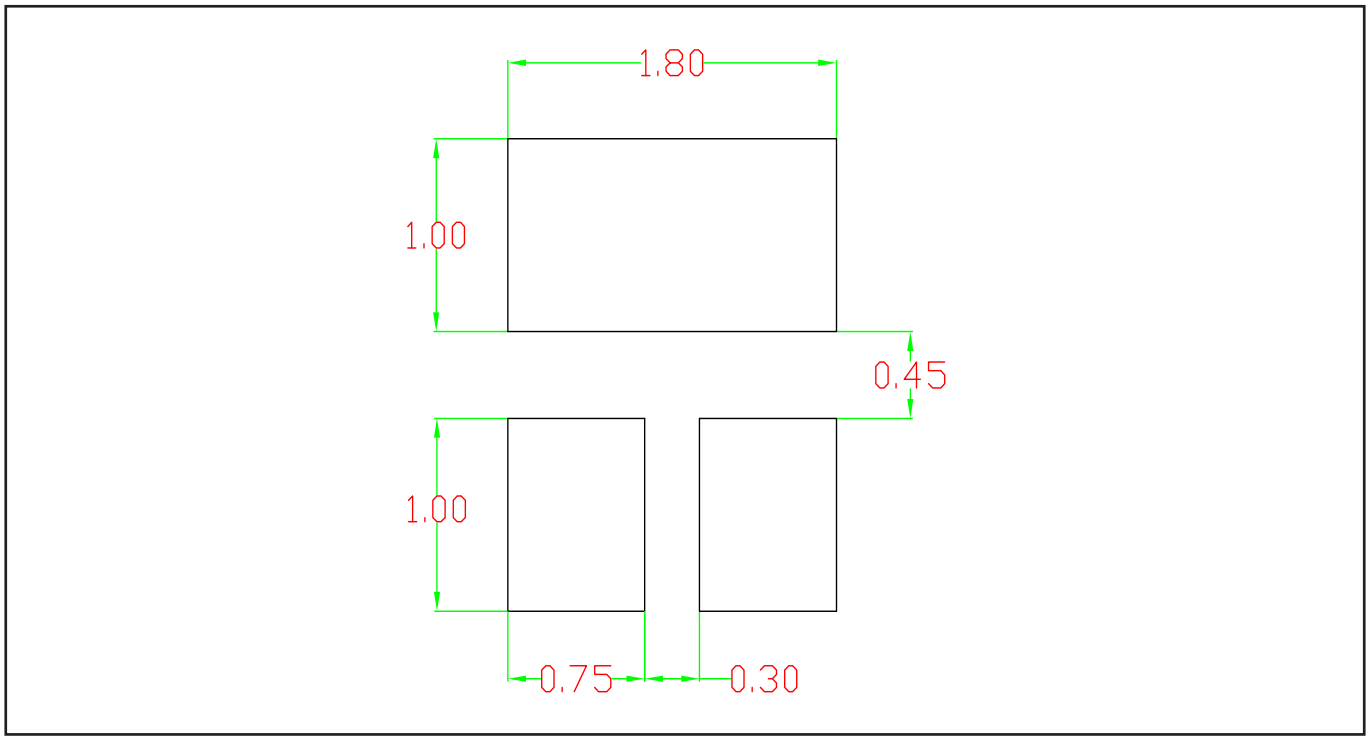


Notes:
General Tolerances +/- 0.05mm

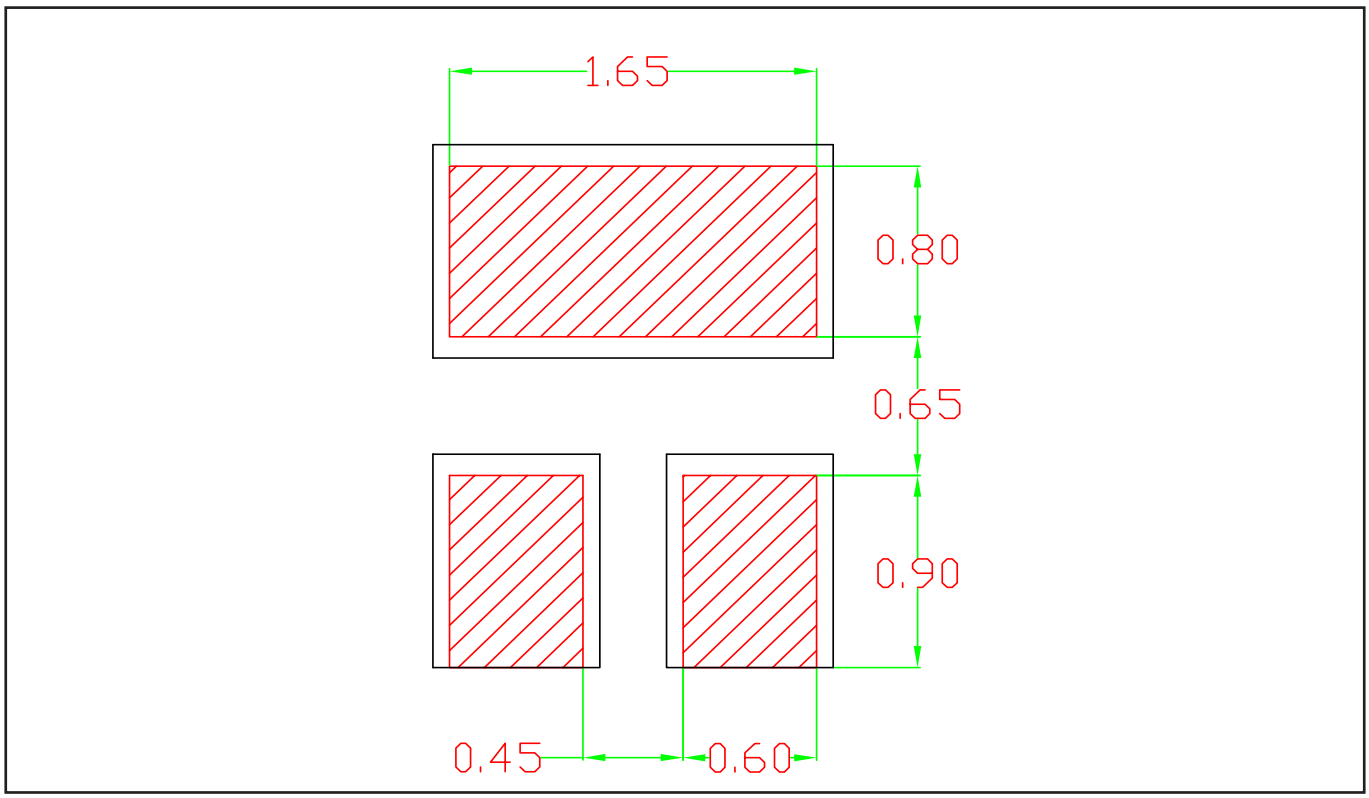
Material

	Material
Substrate	Ceramic
Encapsulant	Silicone
Soldering Surface	Au Plating

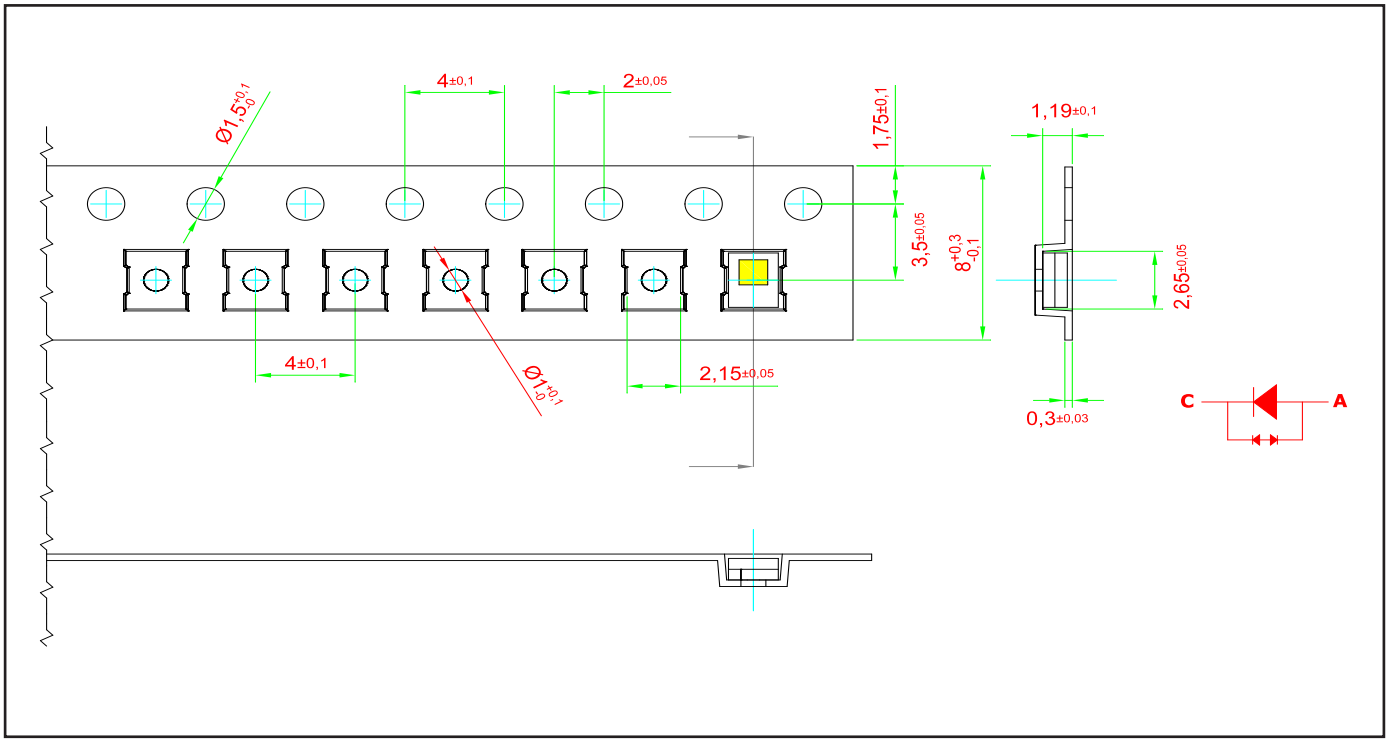
Recommended Solder Pad



Recommended Solder Stencil Design

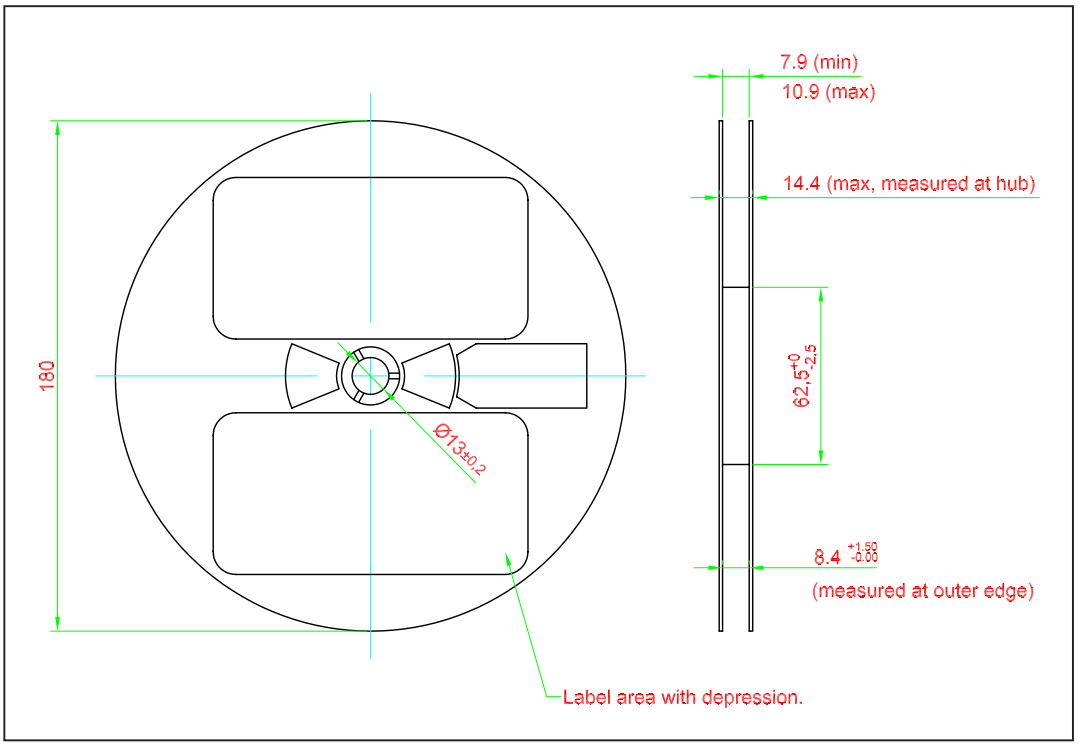


Taping and orientation



Notes:
Please refer to DOMINANT LED Handling Procedure‘s application note for additional information.

Packaging Specification

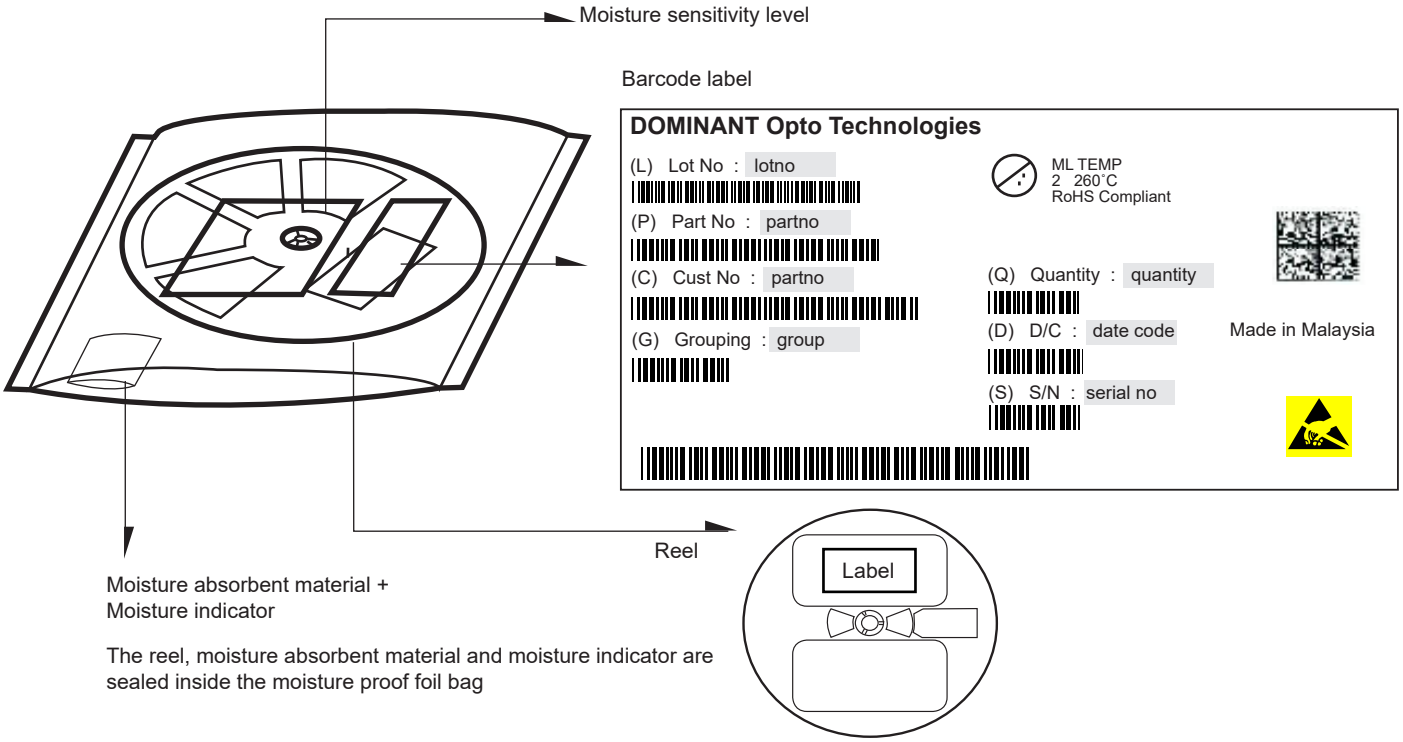


	Reel Diameter (mm)	Quantity (pcs)	*Ordering Number
Standard Packing	180	2000	J1ZY-PZHS-xxx-1

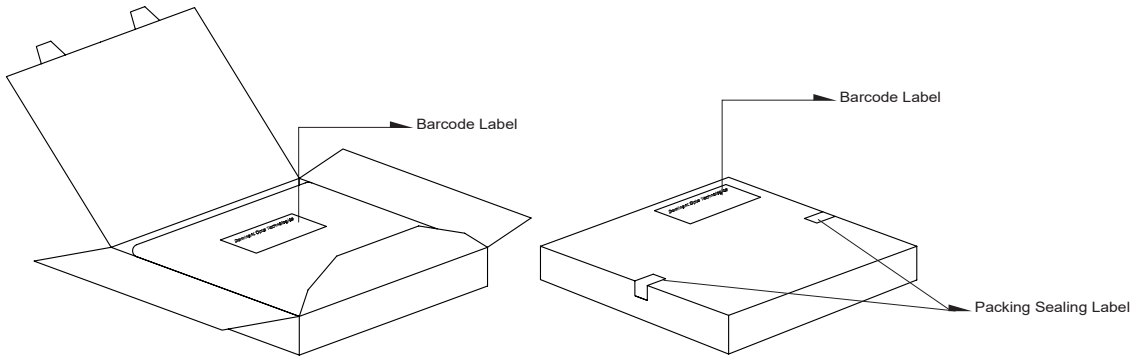
Notes:

* For ordering purpose only. Please consult sales and marketing for details.

Packaging Specification



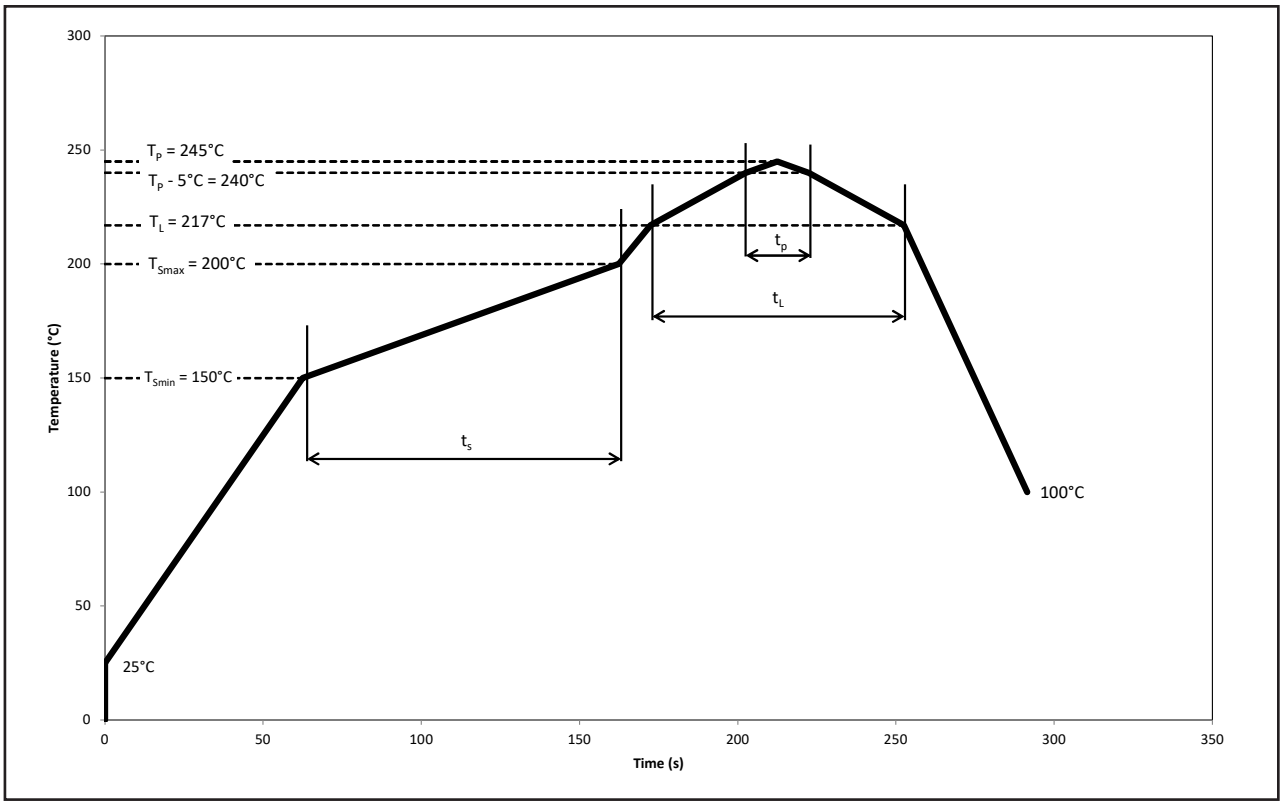
Quantity per bag (pcs)	Average 1pc NagaJo 2025 (g)	1 completed bag (g)
2000	0.0123	190 ± 10



Reel Diameter (mm)	Packing Box Dimensions (mm)
180	210 x 210 x 16

Recommended Pb-free Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E



Profile Feature	Symbol	Pb-Free Assembly			Unit
		Min.	Recommended	Max.	
Ramp-up rate to preheat 25°C to T_{smin}	-	-	2	3	°C/s
Time t_S T_{smin} to T_{smax}	t_S	60	100	120	s
Ramp-up rate to peak T_L to T_P	-	-	2	3	°C/s
Liquidous temperature	T_L	-	217	-	°C
Time above liquidous temperature	t_L	60	80	150	s
Peak temperature	T_p	-	245	260	°C
Time within 5°C of the specified peak temperature T_P - 5°C	t_p	10	20	30	s
Ramp-down rate T_P to 100°C	-	-	3	6	°C/s
Time 25°C to T_P	-	-	-	480	s

Appendix

1) Brightness:

1.1 Luminous intensity is measured at current pulse 25 ms(typ) with an internal reproducibility of ± 8 % and an expanded uncertainty of ± 11 % (according to GUM with a coverage factor of k=3).

1.2 Luminous flux is measured at current pulse 25 ms(typ) with an internal reproducibility of ± 8 % and an expanded uncertainty of ± 11 % (according to GUM with a coverage factor of k=3).

1.3 Radiant intensity is measured at current pulse 25 ms(typ) with an internal reproducibility of ± 8 % and an expanded uncertainty of ± 11 % (according to GUM with a coverage factor of k=3).

1.4 Radiant flux is measured at current pulse 25 ms(typ) with an internal reproducibility of ± 8 % and an expanded uncertainty of ± 11 % (according to GUM with a coverage factor of k=3).

2) Color:

2.1 Chromaticity coordinate groups are measured at current pulse 25 ms(typ) with an internal reproducibility of ± 0.005 and an expanded uncertainty of ± 0.01 (accordingly to GUM with a coverage factor of k=3).

2.2 Dominant wavelength is measured at current pulse 25 ms(typ) with an internal reproducibility of ± 0.5nm and an expanded uncertainty of ± 1nm (accordingly to GUM with a coverage factor of k=3).

3) Voltage:

3.1 Forward Voltage, Vf is measured when a current pulse of 8 ms(typ) with an internal reproducibility of ± 0.05V and an expanded uncertainty of ± 0.1V (accordingly to GUM with a coverage factor of k=3).

4) Typical Values:

4.1 At special conditions of LED manufacturing processes, typical data or calculated correlations of technical parameters only reflect the statistical figures. But not necessarily correspond to the actual parameters of each single product, which could differ from the typical data or calculated correlations or the typical characteristic line. These typical data may change whenever technical improvements happen.

5) Tolerance of Measure

5.1 Unless otherwise noted in drawing, tolerances are specified with ± 0.1 and dimension are specifiec in mm.

Revision History

Page	Subjects	Date of Modification
-	Initial Release	18 Dec 2019
11, 12	Update Package Specification Update Recommended Pb-free Soldering Profile	23 Feb 2022
2	Not for New Design: J1ZY-PZHS-8W8X-1	22 Dec 2023

NOTE

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